
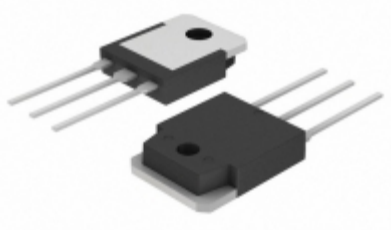

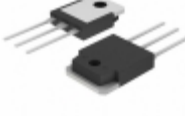

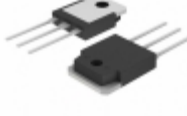

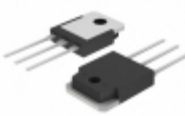
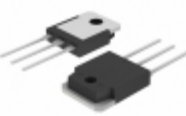
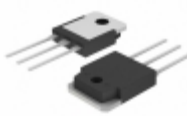
 	<h2 style="color: red;">FQA10N60C</h2>
	<p>Hersteller-Teilenummer: FQA10N60C</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 600V 10A TO-3P</p> <hr/> <p>Datenblätter:  FQA10N60C.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 1150 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p style="text-align: center;"><small>YIC International Co., Limited.</small></p>	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQA10N60C
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 600V 10A TO-3P
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1150 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3PN
Verlustleistung (max)	192W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	10A (Tc)
Rds On (Max) @ Id, Vgs	730 mOhm @ 5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	57nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2040pF @ 25V
Verpackung	Tube

FQA10N60C ist neu im Original, Suche FQA10N60C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA10N60C Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQA10N60C: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQA10N60C AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 10A TO-3P</p>	 <p>FQA10N80 Fairchild/ON Semiconductor MOSFET N-CH 800V 9.8A TO-3P</p>	 <p>FQA10N80_F109 AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 9.8A TO-3P</p>	 <p>FQA10N80C-F109 AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 10A TO-3P</p>
 <p>FQA10N60 FSC FQA10N60 FSC</p>	 <p>FQA10N80 AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 9.8A TO-3P</p>	 <p>FQA10N80_F109 Fairchild/ON Semiconductor MOSFET N-CH 800V 9.8A TO-3P</p>	 <p>FQA10N80C_F109 Fairchild/ON Semiconductor FQA10N80C_F109 Fairchild/ON Semiconductor</p>

heiße Teile

Mehr

FQA10N60C	FQA10N80C	FQA10N80C	FQA10N80C_F109	FQA11N90
FQA11N90	FQA11N90C	FQA11N90C	FQA11N90C	FQA11N90C_F109
FQA11N90_F109	FQA12N60C	FQA12P20	FQA12P20	FQA13N50
FQA13N50	FQA13N50C	FQA13N50C	FQA13N50C_F109	FQA13N80
FQA13N80	FQA13N80_F109	FQA140N10	FQA140N10	FQA14N30
FQA14N30	FQA160N08	FQA160N08	FQA16N50	FQA16N50
FQA170N06	FQA170N06	FQA18N40	FQA18N50	FQA19N20C
FQA19N20C	FQA19N20L	FQA19N20L	FQA19N60	FQA19N60
FQA20N40	FQA20N40	FQA20N50	FQA20N60	FQA20N80
FQA24N50	FQA24N50	FQA24N50F	FQA24N50F	FQA24N60

Contact us: Info@Y-IC.com

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